

**STD1805**

# LOW VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

PRELIMINARY DATA

Ordering Code	Marking	Shipment
STD1805T4	D1805	Tape & Reel
STD1805-1	D1805	Tube

- VERY LOW COLLECTOR TO Emitter SATURATION VOLTAGE
- HIGH CURRENT GAIN CHARACTERISTIC
- FAST-SWITCHING SPEED
- THROUGH-HOLE IPAK (TO-251) POWER PACKAGE IN TUBE (Suffix "-1")
- SURFACE-MOUNTING DPAK (TO-252) POWER PACKAGE IN TAPE & REEL (Suffix "T4")

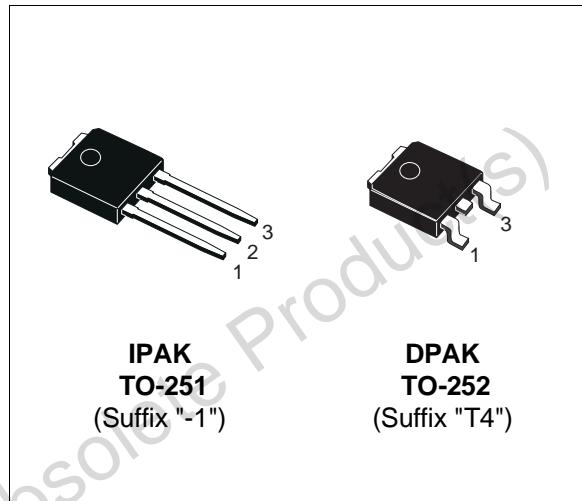
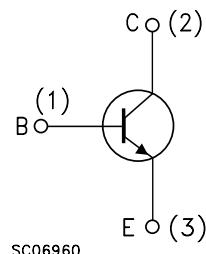
**APPLICATIONS:**

- CCFL DRIVERS
- VOLTAGE REGULATORS
- RELAY DRIVERS
- HIGH EFFICIENCY LOW VOLTAGE SWITCHING APPLICATIONS

**DESCRIPTION**

The device is manufactured in NPN Planar Technology by using a "Base Island" layout.

The resulting Transistor shows exceptional high gain performance coupled with very low saturation voltage.

**INTERNAL SCHEMATIC DIAGRAM****ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage ( $I_E = 0$ )	150	V
$V_{CEO}$	Collector-Emitter Voltage ( $I_B = 0$ )	60	V
$V_{EBO}$	Emitter-Base Voltage ( $I_C = 0$ )	7	V
$I_C$	Collector Current	5	A
$I_{CM}$	Collector Peak Current ( $t_p < 5 \text{ ms}$ )	10	A
$I_B$	Base Current	2	A
$P_{tot}$	Total Dissipation at $T_c = 25^\circ\text{C}$	15	W
$T_{stg}$	Storage Temperature	-65 to 150	°C
$T_j$	Max. Operating Junction Temperature	150	°C

## THERMAL DATA

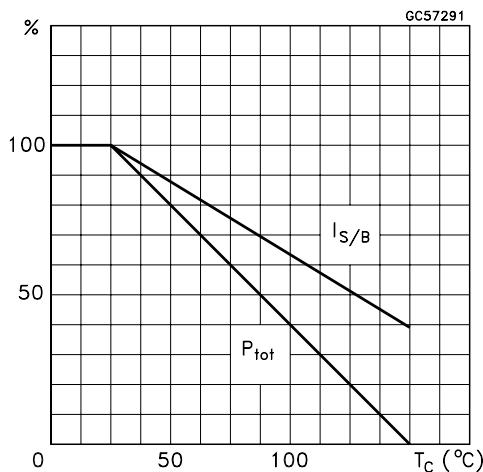
$R_{\text{thj-case}}$	Thermal Resistance Junction-case	Max	8.33	$^{\circ}\text{C/W}$
-----------------------	----------------------------------	-----	------	----------------------

ELECTRICAL CHARACTERISTICS ( $T_{\text{case}} = 25^{\circ}\text{C}$  unless otherwise specified)

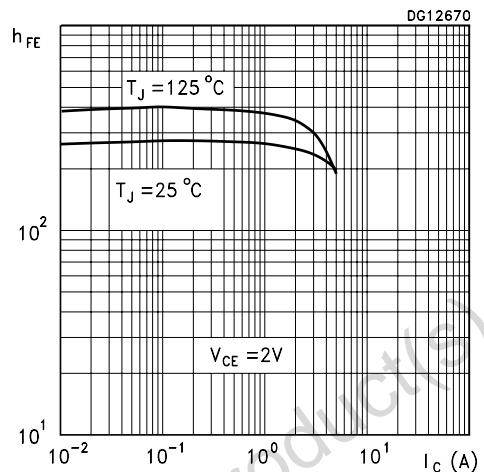
Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
$I_{\text{CBO}}$	Collector Cut-off Current ( $I_E = 0$ )	$V_{\text{CB}} = 40 \text{ V}$				0.1	$\mu\text{A}$
$I_{\text{EBO}}$	Emitter Cut-off Current ( $I_C = 0$ )	$V_{\text{EB}} = 4 \text{ V}$				0.1	$\mu\text{A}$
$V_{(\text{BR})\text{CBO}}$	Collector-Base Breakdown Voltage ( $I_E = 0$ )	$I_C = 100 \mu\text{A}$		150			$\text{V}$
$V_{(\text{BR})\text{CEO}}^*$	Collector-Emitter Breakdown Voltage ( $I_B = 0$ )	$I_C = 1 \text{ mA}$		60			$\text{V}$
$V_{(\text{BR})\text{EBO}}$	Emitter-Base Breakdown Voltage ( $I_C = 0$ )	$I_E = 100 \mu\text{A}$		7			$\text{V}$
$V_{\text{CE}(\text{sat})}^*$	Collector-Emitter Saturation Voltage	$I_C = 100 \text{ mA}$ $I_C = 2 \text{ A}$ $I_C = 3 \text{ A}$ $I_C = 5 \text{ A}$	$I_B = 5 \text{ mA}$ $I_B = 50 \text{ mA}$ $I_B = 150 \text{ mA}$ $I_B = 200 \text{ mA}$		150 200	50 300 400 600	$\text{mV}$ $\text{mV}$ $\text{mV}$ $\text{mV}$
$V_{\text{BE}(\text{sat})}^*$	Base-Emitter Saturation Voltage	$I_C = 2 \text{ A}$	$I_B = 100 \text{ mA}$		0.9	1.2	$\text{V}$
$h_{\text{FE}}^*$	DC Current Gain	$I_C = 100 \text{ mA}$ $I_C = 5 \text{ A}$ $I_C = 10 \text{ A}$	$V_{\text{CE}} = 2 \text{ V}$ $V_{\text{CE}} = 2 \text{ V}$ $V_{\text{CE}} = 2 \text{ V}$	200 85 20		400	
$f_T$	Transition frequency	$V_{\text{CE}} = 10 \text{ V}$	$I_C = 50 \text{ mA}$		150		$\text{MHz}$
$C_{\text{CBO}}$	Collector-Base Capacitance	$V_{\text{CB}} = 10 \text{ V}$	$f = 1 \text{ MHz}$		50		$\text{pF}$
$t_{\text{ON}}$ $t_s$ $t_f$	RESISTIVE LOAD Turn-on Time Storage Time Fall Time	$I_C = 1 \text{ A}$ $I_{B1} = -I_{B2} = 0.1 \text{ A}$	$V_{\text{CC}} = 30 \text{ V}$		50 1.35 120		$\text{ns}$ $\mu\text{s}$ $\text{ns}$

\* Pulsed: Pulse duration = 300 $\mu\text{s}$ , duty cycle = 1.5 %

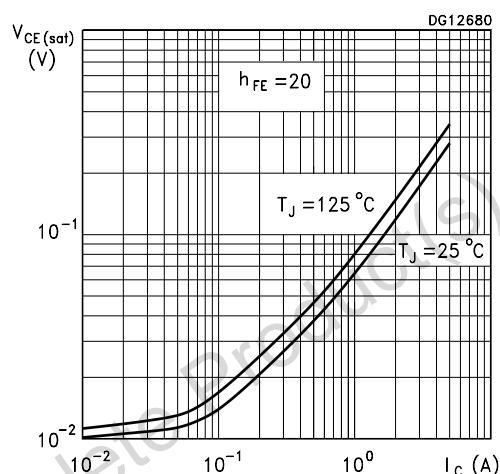
Derating Curve



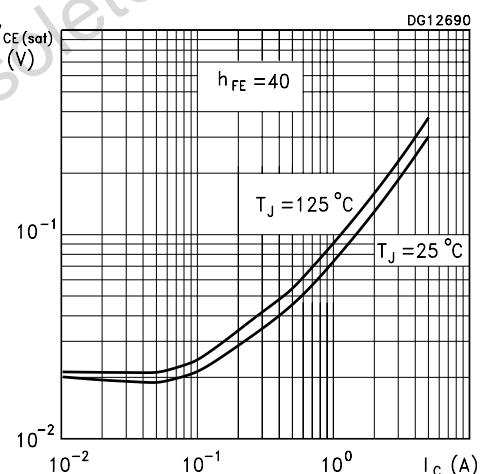
DC Current Gain



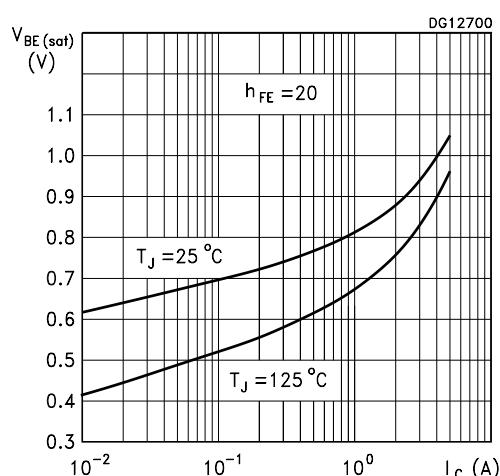
Collector-Emitter Saturation Voltage



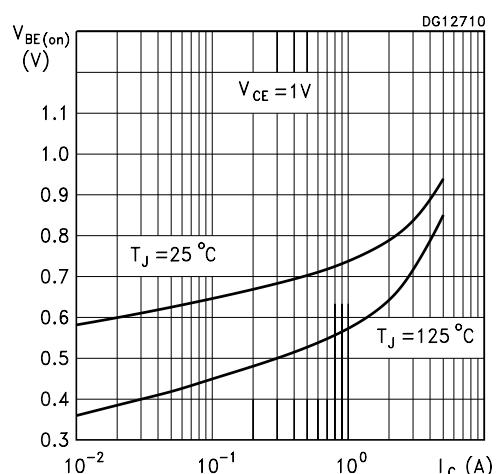
Collector-Emitter Saturation Voltage



Base-Emitter Saturation Voltage

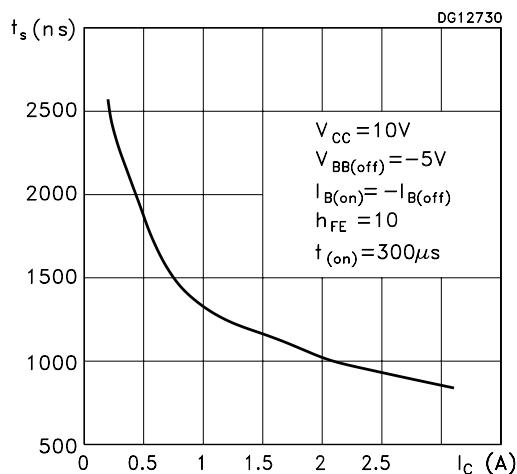


Base-Emitter On Voltage

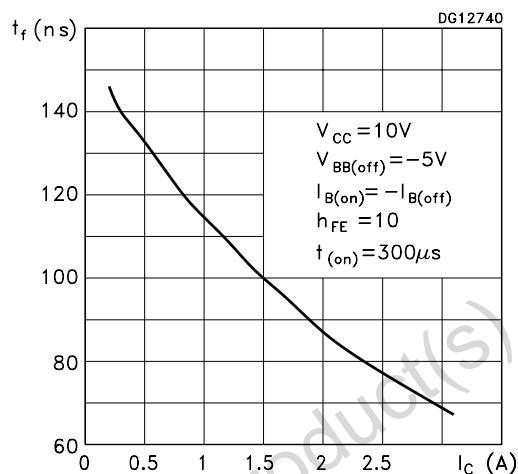


## STD1805

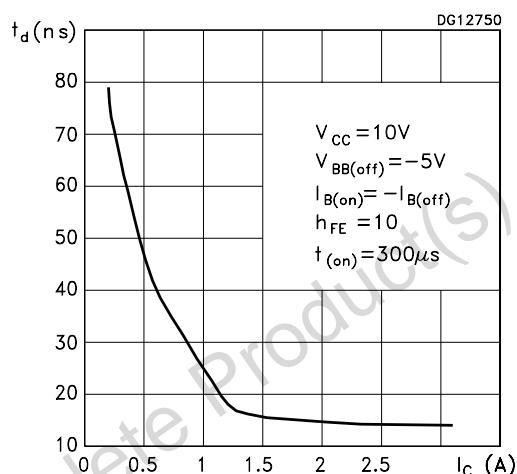
Switching Times Resistive Load



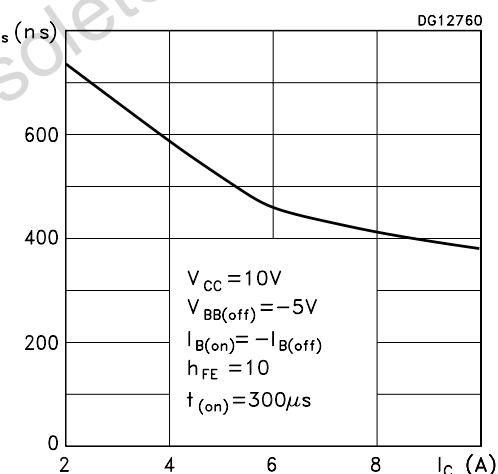
Switching Times Resistive Load



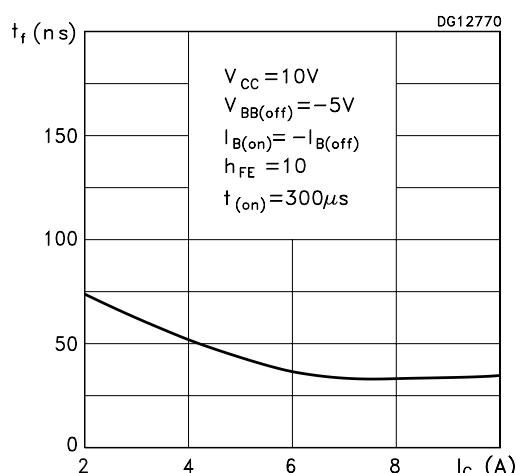
Switching Times Resistive Load

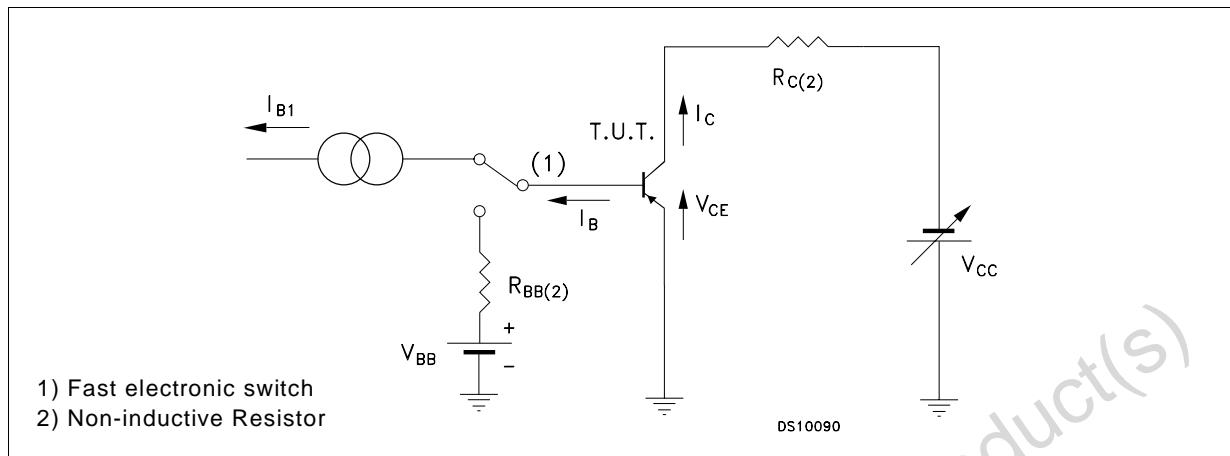


Switching Times Inductive Load



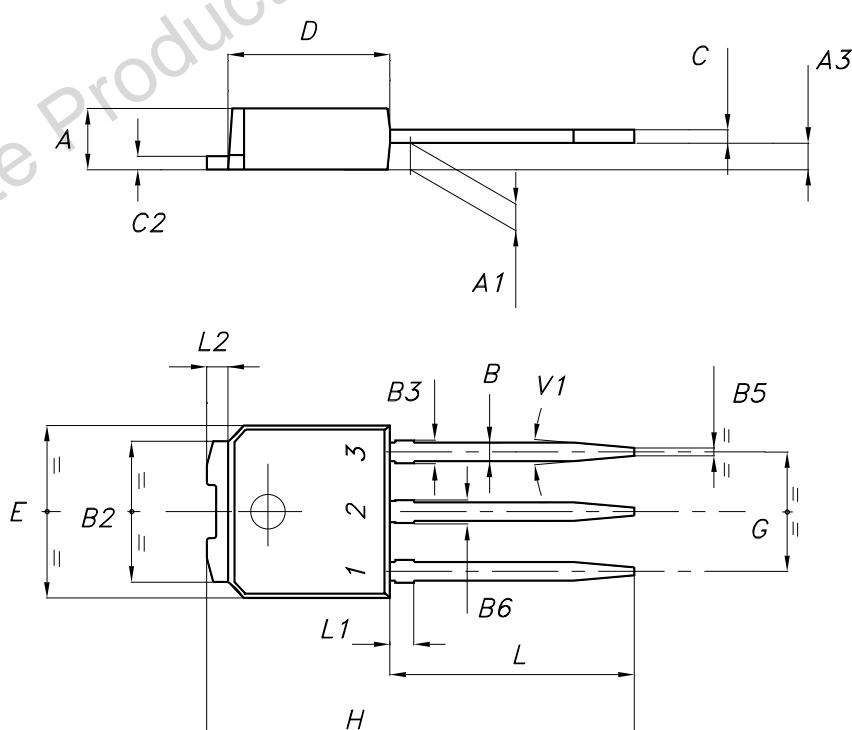
Switching Times Inductive Load



**Figure 1:** Resistive Load Switching Test Circuit.

## **TO-251 (IPAK) MECHANICAL DATA**

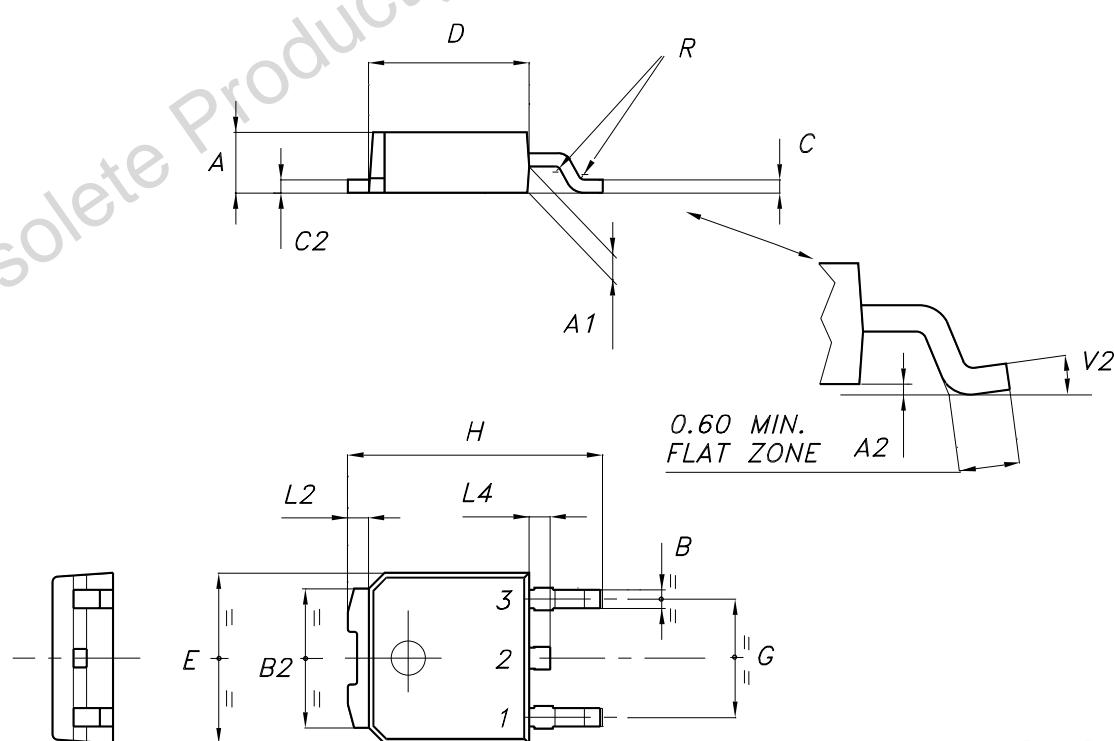
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	2.20		2.40	0.087		0.094
A1	0.90		1.10	0.035		0.043
A3	0.70		1.30	0.028		0.051
B	0.64		0.90	0.025		0.035
B2	5.20		5.40	0.204		0.213
B3			0.85			0.033
B5		0.30			0.012	
B6			0.95			0.037
C	0.45		0.60	0.018		0.024
C2	0.48		0.60	0.019		0.024
D	6.00		6.20	0.237		0.244
E	6.40		6.60	0.252		0.260
G	4.40		4.60	0.173		0.181
H	15.90		16.30	0.626		0.642
L	9.00		9.40	0.354		0.370
L1	0.80		1.20	0.031		0.047
L2		0.80	1.00		0.031	0.039
V1		10°			10°	



P032N\_E

## TO-252 (DPAK) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	2.20		2.40	0.087		0.094
A1	0.90		1.10	0.035		0.043
A2	0.03		0.23	0.001		0.009
B	0.64		0.90	0.025		0.035
B2	5.20		5.40	0.204		0.213
C	0.45		0.60	0.018		0.024
C2	0.48		0.60	0.019		0.024
D	6.00		6.20	0.236		0.244
E	6.40		6.60	0.252		0.260
G	4.40		4.60	0.173		0.181
H	9.35		10.10	0.368		0.398
L2		0.8			0.031	
L4	0.60		1.00	0.024		0.039
V2	0°		8°	0°		0°



P032P\_B

Obsolete Product(s) - Obsolete Product(s)

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specification mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a trademark of STMicroelectronics.

All other names are the property of their respective owners.

© 2003 STMicroelectronics – All Rights reserved  
STMicroelectronics GROUP OF COMPANIES

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -  
Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States.

<http://www.st.com>